PΛN	ĴΪΤ
	SEMI CONDUCTOR

## 20V N-Channel Enhancement Mode MOSFET

Current

1.3A

#### Features

Voltage

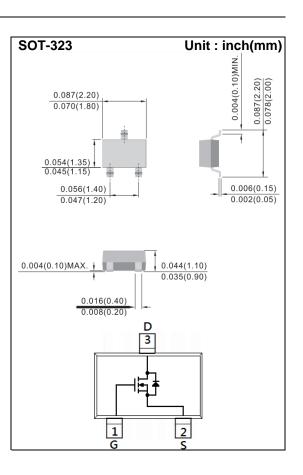
• RDS(ON) , VGS@4.5V, ID@1.3A<77mΩ

20 V

- RDS(ON), VGS@2.5V, ID@1.0A<90mΩ
- RDS(ON), VGS@1.8V, ID@0.7A<120mΩ
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc.
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

#### **Mechanical Data**

- Case: SOT-323 Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.00018 ounces, 0.005 grams
- Marking: C06



### **Maximum Ratings and Thermal Characteristics** (T<sub>A</sub>=25<sup>°</sup>C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V <sub>DS</sub>	20	V
Gate-Source Voltage		V <sub>GS</sub>	<u>+</u> 12	V
Continuous Drain Current		I <sub>D</sub>	1.3	А
Pulsed Drain Current (Note 4)		I <sub>DM</sub>	5.2	А
Power Dissipation	T <sub>a</sub> =25°C	P <sub>D</sub>	350	mW
	Derate above 25°C		2.8	mW/°C
Operating Junction and Storage Temperature Range		T <sub>J</sub> ,T <sub>STG</sub>	-55~150	°C
Typical Thermal resistance - Junction to Ambient <sup>(Note 3)</sup>		$R_{ extsf{ heta}JA}$	357	°C/W



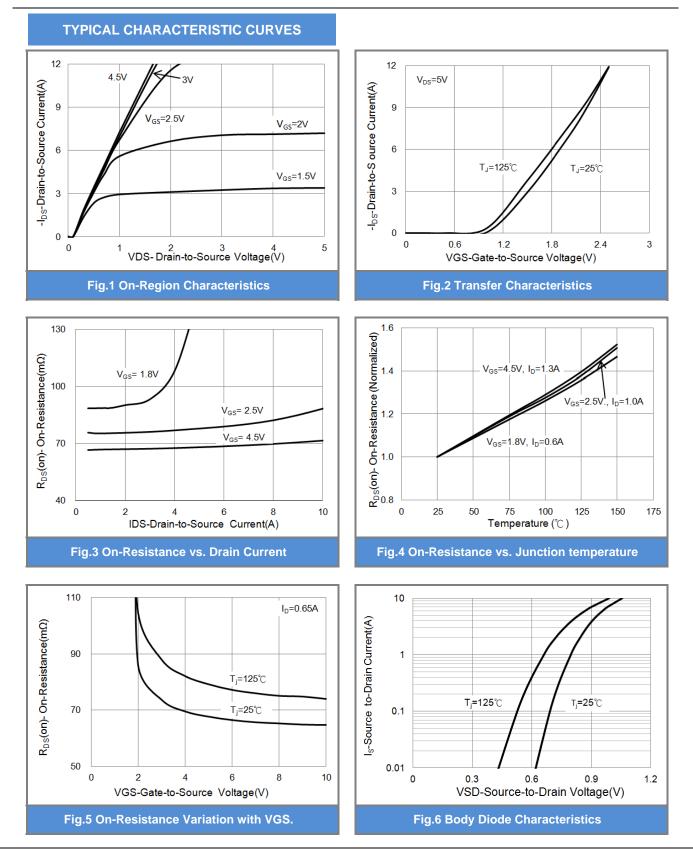
## **Electrical Characteristics** ( $T_A=25^{\circ}C$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	$BV_{DSS}$	V <sub>GS</sub> =0V, I <sub>D</sub> =250uA	20	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=250$ uA	0.4	0.67	1.2	V
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =4.5V, I <sub>D</sub> =1.3A	-	66	77	mΩ
		V <sub>GS</sub> =2.5V, I <sub>D</sub> =1.0A	-	75	90	
		V <sub>GS</sub> =1.8V, I <sub>D</sub> =0.7A	_	90	120	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =20V, V <sub>GS</sub> =0V	-	-0.01	1	uA
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = <u>+</u> 12V, V <sub>DS</sub> =0V	-	<u>+</u> 10	<u>+</u> 100	nA
Dynamic				_		
Total Gate Charge	$Q_g$	V <sub>DS</sub> =10V, I <sub>D</sub> =1.3A, V <sub>GS</sub> =4.5V <sup>(Note 1,2)</sup>	-	4.6	-	nC
Gate-Source Charge	$Q_gs$		_	0.8	-	
Gate-Drain Charge	$Q_gd$		-	1	-	
Input Capacitance	Ciss	V <sub>DS</sub> =10V, V <sub>GS</sub> =0V,	-	350	-	pF
Output Capacitance	Coss		-	40	-	
Reverse Transfer Capacitance	Crss	f=1.0MHZ	-	29	-	
Switching						
Turn-On Delay Time	td <sub>(on)</sub>		-	4	-	
Turn-On Rise Time	tr	$V_{DD}$ =10V, I <sub>D</sub> =1.3A, $V_{GS}$ =4.5V, $R_{G}$ =6 $\Omega$ <sup>(Note 1.2)</sup>	-	47	-	ns
Turn-Off Delay Time	td <sub>(off)</sub>		-	18	-	
Turn-Off Fall Time	tf	$R_{G}=0\Omega$	-	10	-	
Drain-Source Diode						
Maximum Continuous Drain-Source	I <sub>s</sub>		-	-	0.5	А
Diode Forward Current	.3					
Diode Forward Voltage	$V_{SD}$	I <sub>S</sub> =1.0A, V <sub>GS</sub> =0V	-	0.75	1.2	V

NOTES :

- 1. Pulse width200us, Duty cycle
- 2. Essentially independent of operating temperature typical characteristics.
- 3. RoJA is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
- 4. The maximum current rating is package limited







**TYPICAL CHARACTERISTIC CURVES** 5 V<sub>DS</sub>= 10V ID=1.3A Gate-Source Voltage-V<sub>GS</sub>(Volts) 4 3 2 1 0 0 1 3 4 5 2 Qg(nC) Fig.7 Gate-Charge Characteristics

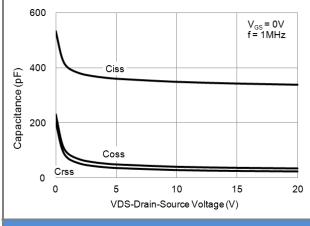
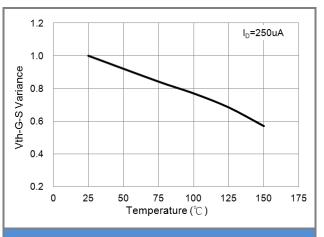


Fig.9 Capacitance vs. Drain-Source Voltage.





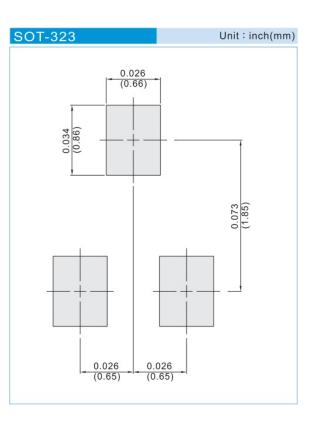




### PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version
PJC7406_R1_00001	SOT-323	3K pcs / 7" reel	C06	Halogen free
PJC7406_R2_00001	SOT-323	12K pcs / 13" reel	C06	Halogen free

### **MOUNTING PAD LAYOUT**







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